## Thermally-Enhanced High Power RF LDMOS FET 80 W, 28 V, 2110 - 2170 MHz

## Description

The PTFB210801FA LDMOS FET is designed for use in multi-standard cellular power amplifier applications in the 2110 to 2170 MHz frequency band. Features include input and output matching, high gain and thermally-enhanced packages with earless flanges. Manufactured with Infineon's advanced LDMOS process, this device provides excellent thermal performance and superior reliability.


PTFB210801FA
Package H-37265-2


## Features

- Broadband internal matching
- Typical single-carrier WCDMA performance at $2170 \mathrm{MHz}, 28 \mathrm{~V}$
- Average output power $=25 \mathrm{~W}$
- Linear Gain $=18.5 \mathrm{~dB}$
- Efficiency = 32.5\%
- Adjacent channel power $=-37 \mathrm{dBc}$
- Typical CW performance, $2170 \mathrm{MHz}, 28 \mathrm{~V}$
- Output power at $P_{1 d B}=80 \mathrm{~W}$
- Efficiency = 55\%
- Integrated ESD protection
- Capable of handling 10:1 VSWR @ 28 V, 80 W (CW) output power
- Pb-free and RoHS compliant


## RF Characteristics

Two-carrier WCDMA Measurements (tested in Infineon test fixture)
$\mathrm{V}_{\mathrm{DD}}=28 \mathrm{~V}, \mathrm{I}_{\mathrm{DQ}}=750 \mathrm{~mA}$, POUT $=20 \mathrm{~W}$ average, $f_{1}=2160 \mathrm{MHz}, f_{2}=2170 \mathrm{MHz}, 3 G P P$ signal, channel bandwidth $=3.84 \mathrm{MHz}$, peak/average $=8 \mathrm{~dB}$ @ $0.01 \%$ CCDF

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Gain | $G_{p s}$ | 18 | 18.5 | - | dB |
| Drain Efficiency | $\eta \mathrm{D}$ | 28 | 31 | - | $\%$ |
| Intermodulation Distortion | IMD | - | -30 | -28 | dBc |

All published data at $T_{\text {CASE }}=25^{\circ} \mathrm{C}$ unless otherwise indicated

DC Characteristics

| Characteristic | Conditions | Symbol | Min | Typ | Max | Unit |
| :--- | :--- | :---: | :---: | :---: | :---: | :---: |
| Drain-Source Breakdown Voltage | $\mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{I}_{\mathrm{DS}}=10 \mathrm{~mA}$ | $\mathrm{~V}_{(\mathrm{BR}) \mathrm{DSS}}$ | 65 | - | - | V |
| Drain Leakage Current | $\mathrm{V}_{\mathrm{DS}}=28 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}$ | $\mathrm{I}_{\mathrm{DSS}}$ | - | - | 1.0 | $\mu \mathrm{~A}$ |
| Drain Leakage Current | $\mathrm{V}_{\mathrm{DS}}=63 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}$ | $\mathrm{I}_{\mathrm{DSS}}$ | - | - | 10.0 | $\mu \mathrm{~A}$ |
| On-State Resistance | $\mathrm{V}_{\mathrm{GS}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=0.1 \mathrm{~V}$ | $\mathrm{R}_{\mathrm{DS}(\mathrm{on})}$ | - | 0.05 | - | $\Omega$ |
| Operating Gate Voltage | $\mathrm{V}_{\mathrm{DS}}=30 \mathrm{~V}, \mathrm{I}_{\mathrm{DQ}}=750 \mathrm{~mA}$ | $\mathrm{~V}_{\mathrm{GS}}$ | 2.3 | 3.0 | 3.3 | V |
| Gate Leakage Current | $\mathrm{V}_{\mathrm{GS}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=0 \mathrm{~V}$ | $\mathrm{I}_{\mathrm{GSS}}$ | - | - | 1.0 | $\mu \mathrm{~A}$ |

## Maximum Ratings

| Parameter | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Drain-Source Voltage | $\mathrm{V}_{\mathrm{DSS}}$ | 65 | V |
| Gate-Source Voltage | $\mathrm{V}_{\mathrm{GS}}$ | -6 to +10 | V |
| Junction Temperature | $\mathrm{T}_{\mathrm{J}}$ | 200 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $\mathrm{T}_{\text {STG }}$ | -40 to +150 | ${ }^{\circ} \mathrm{C}$ |
| Thermal Resistance $\left(\mathrm{T}_{\mathrm{CASE}}=70^{\circ} \mathrm{C}, 80 \mathrm{~W} \mathrm{CW}\right)$ | $\mathrm{R}_{\theta \mathrm{JC}}$ | 0.50 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

## Ordering Information

| Type and Version | Order Code | Package Description | Shipping |
| :--- | :--- | :--- | :--- |
| PTFB210801FA V1 R0 | PTFB210801FAV1R0XTMA1 | H-37265-2, earless flange | Tape \& Reel, 50 pcs |
| PTFB210801FA V1 R250 | PTFB210801FAV1R250XTMA1 | H-37265-2, earless flange | Tape \& Reel, 250 pcs |

Typical Performance (data taken in a production test fixture)



CW Performance vs. Temperature
$\mathrm{V}_{\mathrm{DD}}=28 \mathrm{~V}, \mathrm{I}_{\mathrm{DQ}}=750 \mathrm{~mA}, f=2140 \mathrm{MHz}$



## Typical Performance (cont.)




Broadband Circuit Impedance


Z Load

| Frequency | Z Source $\Omega$ |  | Z Load $\Omega$ |  |
| :---: | :---: | :---: | :---: | :---: |
| $\mathbf{M H z}$ | $\mathbf{R}$ | $\mathbf{j X}$ | $\mathbf{R}$ | $\mathbf{j X}$ |
| 2110 | 16.3 | -4.6 | 2.2 | -4.1 |
| 2140 | 13.6 | -4.0 | 2.3 | -4.1 |
| 2170 | 11.3 | -2.9 | 2.2 | -4.4 |

## Reference Circuit



Reference circuit input schematic for $f=2170 \mathrm{MHz}$


Reference circuit output schematic for $f=2170 \mathrm{MHz}$

## Reference Circuit (cont.)

## Description

| DUT | PTFB210801FA |
| :--- | :--- |
| PCB | $0.508 \mathrm{~mm}[.020 "]$ thick, $\varepsilon$ r $=3.66$, Rogers 4350, 1 oz. copper |

## Electrical Characteristics at $\mathbf{2 1 7 0} \mathbf{~ M H z}$

| Transmission Line | Electrical <br> Characteristics | Dimensions: mm | Dimensions: mils |
| :---: | :---: | :---: | :---: |
| Input |  |  |  |
| TL101, TL117 | $0.023 \lambda, 35.71 \Omega$ | $\mathrm{W} 1=1.905, \mathrm{~W} 2=1.905, \mathrm{~W} 3=1.905$ | $\mathrm{W} 1=75, \mathrm{~W} 2=75, \mathrm{~W} 3=75$ |
| TL102, TL115 | $0.012 \lambda, 35.71 \Omega$ | $\mathrm{W} 1=1.905, \mathrm{~W} 2=1.905, \mathrm{~W} 3=1.016$ | $\mathrm{W} 1=75, \mathrm{~W} 2=75, \mathrm{~W} 3=40$ |
| TL103 | $0.021 \lambda, 54.17 \Omega$ | $\mathrm{W}=1.016, \mathrm{~L}=1.778$ | W = 40, L = 70 |
| TL104 |  | $\begin{aligned} & \mathrm{W} 1=9.398, \mathrm{~W} 2=1.270, \mathrm{~W} 3=9.398, \\ & \mathrm{~W} 4=1.270 \end{aligned}$ | $\begin{aligned} & \mathrm{W} 1=370, \mathrm{~W} 2=50, \mathrm{~W} 3=370, \\ & \mathrm{~W} 4=40 \end{aligned}$ |
| TL105 |  | $\mathrm{W} 1=1.024, \mathrm{~W} 2=9.398$ | $\mathrm{W} 1=40, \mathrm{~W} 2=370$ |
| TL106 |  | W1 = 9.398, W2 = 9.398 | $\mathrm{W} 1=370, \mathrm{~W} 2=370$ |
| TL107 | $0.050 \lambda, 53.93 \Omega$ | $\mathrm{W}=1.024, \mathrm{~L}=4.153$ | $\mathrm{W}=40, \mathrm{~L}=164$ |
| TL108 | $0.025 \lambda, 9.59 \Omega$ | $\mathrm{W}=9.398, \mathrm{~L}=1.905$ | $\mathrm{W}=370, \mathrm{~L}=75$ |
| TL109 | $0.019 \lambda, 53.93 \Omega$ | $\mathrm{W}=1.024, \mathrm{~L}=1.605$ | W = 40, L = 63 |
| TL110 | $0.092 \lambda, 53.93 \Omega$ | $\mathrm{W}=1.024, \mathrm{~L}=7.696$ | $\mathrm{W}=40, \mathrm{~L}=303$ |
| TL111 | $0.072 \lambda, 53.93 \Omega$ | $\mathrm{W}=1.024, \mathrm{~L}=5.994$ | $\mathrm{W}=40, \mathrm{~L}=236$ |
| TL112 | $0.011 \lambda, 53.93 \Omega$ | $\mathrm{W} 1=1.024, \mathrm{~W} 2=1.024, \mathrm{~W} 3=0.889$ | $\mathrm{W} 1=40, \mathrm{~W} 2=40, \mathrm{~W} 3=35$ |
| TL113 | $0.212 \lambda, 47.12 \Omega$ | $\mathrm{W}=1.270, \mathrm{~L}=17.577$ | $\mathrm{W}=50, \mathrm{~L}=692$ |
| TL114, TL121 | $0.039 \lambda, 47.12 \Omega$ | W1 = 1.270, W2 = 1.270, W3 = 3.200 | $\mathrm{W} 1=50, \mathrm{~W} 2=50, \mathrm{~W} 3=126$ |
| TL116, TL122, TL123 | $0.016 \lambda, 35.71 \Omega$ | W1 $=1.905, \mathrm{~W} 2=1.905, \mathrm{~W} 3=1.270$ | $\mathrm{W} 1=75, \mathrm{~W} 2=75, \mathrm{~W} 3=50$ |
| TL118, TL120 | $0.004 \lambda, 35.71 \Omega$ | $\mathrm{W}=1.905, \mathrm{~L}=0.361$ | $\mathrm{W}=75, \mathrm{~L}=14$ |
| TL119 | $0.021 \lambda, 54.17 \Omega$ | $\mathrm{W}=1.016, \mathrm{~L}=1.778$ | $\mathrm{W}=40, \mathrm{~L}=70$ |
| TL124 | $0.039 \lambda, 35.71 \Omega$ | $\mathrm{W}=1.905, \mathrm{~L}=3.172$ | $\mathrm{W}=75, \mathrm{~L}=125$ |
| TL125 | $0.048 \lambda, 47.12 \Omega$ | $\mathrm{W}=1.270, \mathrm{~L}=4.013$ | $\mathrm{W}=50, \mathrm{~L}=158$ |
| TL126 | $0.071 \lambda, 47.12 \Omega$ | $\mathrm{W}=1.270, \mathrm{~L}=5.906$ | $\mathrm{W}=50, \mathrm{~L}=233$ |
| TL127, TL128 | $0.005 \lambda, 47.12 \Omega$ | $\mathrm{W}=1.270, \mathrm{~L}=0.406$ | W = 50, L = 16 |
| TL129 |  | $\mathrm{W} 1=1.024, \mathrm{~W} 2=2.032$ | $\mathrm{W} 1=40, \mathrm{~W} 2=80$ |
| TL130, TL131 | $0.012 \lambda, 34.08 \Omega$ | $\mathrm{W}=2.032, \mathrm{~L}=1.016$ | W = 80, L = 40 |
| TL132 |  | $\mathrm{W} 1=2.032, \mathrm{~W} 2=1.024$ | $\mathrm{W} 1=80, \mathrm{~W} 2=40$ |

table continued on page 7

PTFB210801FA

## Reference Circuit (cont.)

## Electrical Characteristics at 2170 MHz

| Transmission Line | Electrical <br> Characteristics | Dimensions: mm | Dimensions: mils |
| :---: | :---: | :---: | :---: |
| Output |  |  |  |
| TL201, TL203 | $0.009 \lambda, 47.12 \Omega$ | $\mathrm{W}=1.270, \mathrm{~L}=0.762$ | W = 50, L= 30 |
| TL202, TL204 | $0.064 \lambda, 47.12 \Omega$ | $\mathrm{W}=1.270, \mathrm{~L}=5.334$ | $\mathrm{W}=50, \mathrm{~L}=210$ |
| TL205, TL206 |  | $\begin{aligned} & \mathrm{W} 1=1.905, \mathrm{~W} 2=2.540, \mathrm{~W} 3=1.905 \\ & \mathrm{~W} 4=2.540 \end{aligned}$ | $\begin{aligned} & \mathrm{W} 1=75, \mathrm{~W} 2=100, \mathrm{~W} 3=75, \\ & \mathrm{~W} 4=100 \end{aligned}$ |
| TL207 |  | $\begin{aligned} \mathrm{W} 1 & =9.398, \mathrm{~W} 2=1.270, \mathrm{~W} 3=9.398 \\ \mathrm{~W} 4 & =1.270 \end{aligned}$ | $\begin{aligned} & \mathrm{W} 1=370, \mathrm{~W} 2=50, \mathrm{~W} 3=370, \\ & \mathrm{~W} 4=50 \end{aligned}$ |
| TL208, TL209 |  | $\mathrm{W}=1.270$ | $\mathrm{W}=50$ |
| TL210 |  | $\mathrm{W} 1=0.002, \mathrm{~W} 2=0.005$, Offset $=0.001$ | $\mathrm{W} 1=2, \mathrm{~W} 2=184$, Offset $=55$ |
| TL211, TL225 | $0.172 \lambda, 17.67 \Omega$ | $\mathrm{W}=4.674, \mathrm{~L}=13.564$ | $\mathrm{W}=184, \mathrm{~L}=534$ |
| TL212 | $0.011 \lambda, 53.93 \Omega$ | $\mathrm{W} 1=1.024, \mathrm{~W} 2=1.024, \mathrm{~W} 3=0.889$ | W1 $=40, \mathrm{~W} 2=40, \mathrm{~W} 3=35$ |
| TL213 |  | $\begin{aligned} & \mathrm{W} 1=9.398, \mathrm{~W} 2=0.889, \mathrm{~W} 3=9.398 \\ & \mathrm{~W} 4=0.889 \end{aligned}$ | $\begin{aligned} & \mathrm{W} 1=370, \mathrm{~W} 2=35, \mathrm{~W} 3=370, \\ & \mathrm{~W} 4=35 \end{aligned}$ |
| TL214 | $0.016 \lambda, 9.59 \Omega$ | $\mathrm{W}=9.398, \mathrm{~L}=1.219$ | W = 370, L = 48 |
| TL215 | $0.032 \lambda, 53.93 \Omega$ | $\mathrm{W}=1.024, \mathrm{~L}=2.713$ | $\mathrm{W}=40, \mathrm{~L}=107$ |
| TL216 | $0.185 \lambda, 53.93 \Omega$ | $\mathrm{W}=1.024, \mathrm{~L}=15.491$ | W = 40, L = 610 |
| TL217, TL228 | $0.002 \lambda, 35.71 \Omega$ | $\mathrm{W} 1=1.905, \mathrm{~W} 2=1.905, \mathrm{~W} 3=0.127$ | $\mathrm{W} 1=75, \mathrm{~W} 2=75, \mathrm{~W} 3=5$ |
| TL218 |  | $\mathrm{W} 1=9.398, \mathrm{~W} 2=9.398$ | $\mathrm{W} 1=370, \mathrm{~W} 2=370$ |
| TL219 |  | $\mathrm{W} 1=1.024, \mathrm{~W} 2=9.398$ | $\mathrm{W} 1=40, \mathrm{~W} 2=370$ |
| TL220, TL227 | $0.068 \lambda, 35.71 \Omega$ | $\mathrm{W}=1.905, \mathrm{~L}=5.588$ | $\mathrm{W}=75, \mathrm{~L}=220$ |
| TL221, TL222 | $0.016 \lambda, 35.71 \Omega$ | $\mathrm{W} 1=1.905, \mathrm{~W} 2=1.905, \mathrm{~W} 3=1.270$ | $\mathrm{W} 1=75, \mathrm{~W} 2=75, \mathrm{~W} 3=50$ |
| TL223 | $0.012 \lambda, 53.93 \Omega$ | $\mathrm{W}=1.024, \mathrm{~L}=0.991$ | $\mathrm{W}=40, \mathrm{~L}=39$ |
| TL224 | $0.011 \lambda, 9.59 \Omega$ | $\mathrm{W}=9.398, \mathrm{~L}=0.813$ | W = 370, L = 32 |
| TL226 |  | $\mathrm{W} 1=0.002, \mathrm{~W} 2=0.005$, Offset $=-0.001$ | $\mathrm{W} 1=2, \mathrm{~W} 2=184$, Offset $=-55$ |

## Reference Circuit (cont.)

## Circuit Assembly Information

Test Fixture Part No. LTN/PTFB210801FA
Find Gerber files for this test fixture on the Infineon Web site at http://www.infineon.com/rfpower


Reference circuit assembly diagram (not to scale)

PTFB210801FA

## Reference Circuit (cont.)

| Components Information |  |  |  |
| :---: | :---: | :---: | :---: |
| Component | Description | Suggested Manufacturer | P/N |
| Input |  |  |  |
| C101, C103 | Capacitor, $10 \mu \mathrm{~F}$ | Digi-Key | 490-4393-2-ND |
| C102, C105 | Chip capacitor, 15 pF | ATC | 800A150GT |
| C104 | Chip capacitor, 1.5 pF | ATC | 800A1T5GR |
| C801, C802, C803 | Capacitor, 1000 pF | Digi-Key | PCC1772CT-ND |
| L1, L2 | Inductor, 22 nH | Coilcraft | 0805CS-220X_BG |
| R101, R103, R104 | Resistor, $10 \Omega$ | Digi-Key | P10GCT-ND |
| R102, R804 | Resistor, $2000 \Omega$ | Digi-Key | P2.0KECT-ND |
| R801 | Resistor, $3000 \Omega$ | Digi-Key | P3.0KECT-ND |
| R802 | Resistor, $1300 \Omega$ | Digi-Key | P1.3KGECT-ND |
| R803 | Resistor, $1200 \Omega$ | Digi-Key | P1.2KGECT-ND |
| S1, S2 | EMI Suppression Capacitor | Digi-Key | NFM18PS105R0J3D |
| S3 | Potentiometer, $2 \mathrm{k} \Omega$ | Digi-Key | 3224W-202ECT-ND |
| S4 | Voltage Regulator | Digi-Key | LM7805 |
| S5 | Transistor | Digi-Key | BCP56 |
|  |  |  |  |
| Output |  |  |  |
| C201, C203 | Capacitor, $10 \mu \mathrm{~F}$ | Digi-Key | 587-1818-2-ND |
| C202, C211 | Chip capacitor, $4.71 \mu \mathrm{~F}$ | ATC | 490-1864-2-ND |
| C204, C212 | Chip capacitor, 18 pF | ATC | 800A180JT |
| C205, C210 | Capacitor, $22 \mu \mathrm{~F}$ | Digi-Key | PCE4444TR-ND |
| C206, C207 | Chip capacitor, 2.7 pF | ATC | 800A2R7BT |
| C208 | Chip capacitor, 2.2 pF | ATC | 800A2R2BT |
| C209 | Chip capacitor, 15 pF | ATC | 800A150GT |

## Package Outline Specifications

## Package H-37265-2



Diagram Notes—unless otherwise specified:

1. Interpret dimensions and tolerances per ASME Y14.5M-1994.
2. Primary dimensions are mm . Alternate dimensions are inches.
3. All tolerances $\pm 0.127$ [.005] unless specified otherwise.
4. Pins: $\mathrm{D}=$ drain, $\mathrm{S}=$ source, $\mathrm{G}=$ gate.
5. Lead thickness: $0.10+0.051 /-0.025$ [. $004+.002 /-.001]$.
6. Exposed metal plane on top and bottom of ceramic insulator.
7. Gold plating thickness: $1.14 \pm 0.38$ micron [ $45 \pm 15$ microinch]

Find the latest and most complete information about products and packaging at the Infineon Internet page http://www.infineon.com/rfpower

## PTFB210801FA V1

Revision History

| Revision | Date | Data Sheet Type | Page | Subjects (major changes since last revision) |
| :--- | :--- | :--- | :--- | :--- |
| 01 | $2011-03-30$ | Production | All | Data Sheet reflects advance specification for product development |
| 01.1 | $2016-06-14$ | Production | 2 | Updated ordering information |

## We Listen to Your Comments

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